

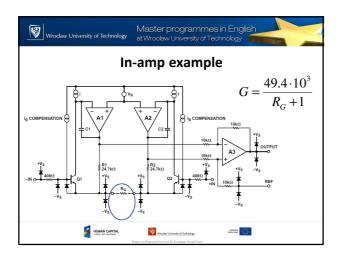


Wrocław		orogrammes in English v University of Technology			
	3op-amp vs. 2 op-amp				
	3op-amp	2 op-amp			
	Single supply can be easy applied.	Limited input voltages for single supply (1st stage can be working with negative output)			
	Signals from both inputs have the same path to output.	Lower CMRR (it comes from the inherent imbalance in the common-mode signal paths of the both inputs especially for high frequencies)			
	HUMAN CAPITAL	Linivensity of Technology			

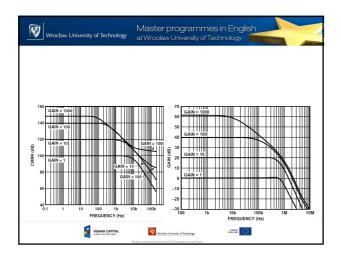


MONOLITHIC IN-AMPs								
Table 3-1. Latest Generation Analog Devices In-Amps Summarized <sup>1</sup>								
Product	Features	Power Supply Current Typ	-3 dB BW Typ (G = 10)	CMR G = 10 (dB) Min	Input Offset Voltage Max	Vos Drift (µV/°C) Max	$RTINoise2(nV/\sqrt{Hz})(G = 10)$	Input Bias Current (nA) Max
AD8221	Precision, high BW	0.9 mA	560 kHz	100 <sup>3</sup>	60 µV	0.4	11 max	1.5
AD620	General-purpose	0.9 mA	800 kHz	95 <sup>3</sup>	125 µV	1	16 max	2
AD8225	Precision gain = 5	1.1 mA	900 kHz4	834,5	150 µV	0.3	45 typ <sup>4</sup>	1.2
AD8220	R-R, IFET input	750 µA	1500 kHz	100	250 µV	5	17 typ	10 pA
AD8222	Dual, precision, high BW	1.8 mA	750 kHz	1003	120 µV	0.4	11 max	2
AD8230	R-R, zero drift	2.7 mA	2 kHz	110	10 µV	10	240 tvp	1
AD8250	High BW, programmable gain	3.5 mA	3.5 MHz	100	100 µV	1	13 typ	15
AD8251	High BW, programmable gain	3.5 mA	3.5 MHz	100	100 µV	1	13 typ	15
AD8553	Auto-zero with shutdown	1.1 mA	1 kHz	100	20 µV	0.1	150 typ	1
AD8555	Zero drift dig prog	2.0 mA	700 kHz <sup>6</sup>	806	10 µV	0.07	32 typ	22
AD8556	Dig prog IA with filters	2.0 mA	700 kHz <sup>6</sup>	80 <sup>6</sup>	10 µV	0.07	32 typ	54
AD622	Low cost	0.9 mA	800 kHz	86 <sup>3</sup>	125 µV	1	14 typ	5
AD621	Precise gain	0.9 mA	800 kHz	93 <sup>3</sup>	$250 \mu V^7$	2.57	$17 \text{ max}^7$	2
AD623	Low cost, S.S.	375 µA	800 kHz	90 <sup>3</sup>	200 µV	2	35 typ	25
AD627	Micropower, S.S.	60 µA	80 kHz	100	250 µV	3	42 typ	10
NOTES								
S.S. = sing	le supply.							
Refer to A	DI website at www.analog.com for	latest produ	cts and specific	ations.				
	RTI noise = $\sqrt{((e_{ni})^2 + (e_{ns(i)})^2)}$ .							
For dc to	60 Hz, 1 kΩ source imbalance.							

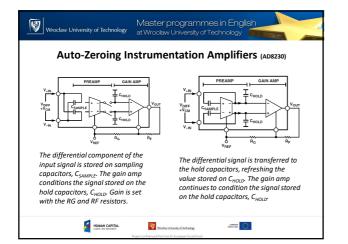




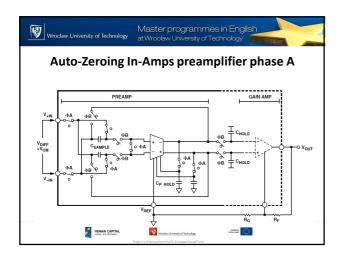


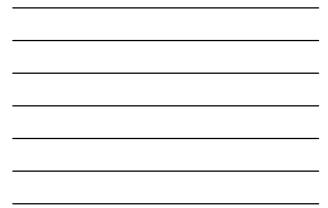


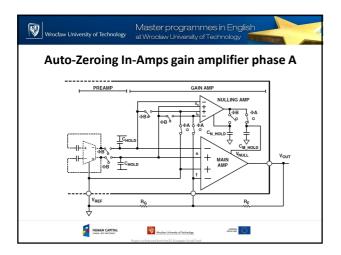




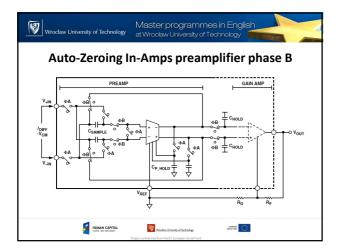




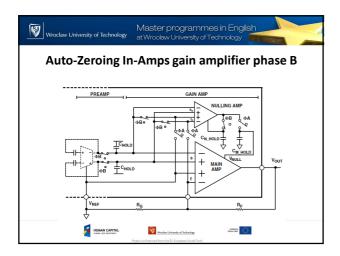


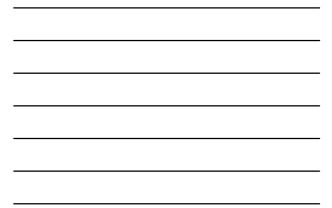


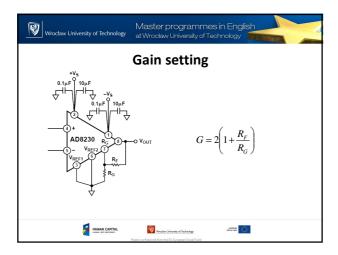




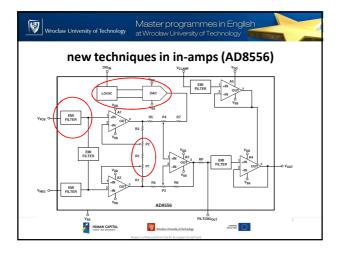




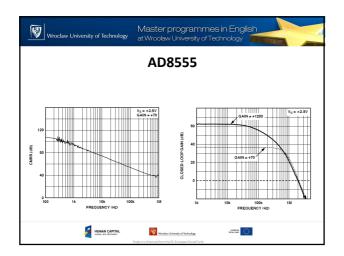


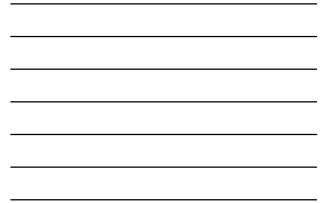


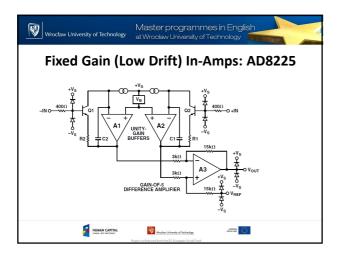




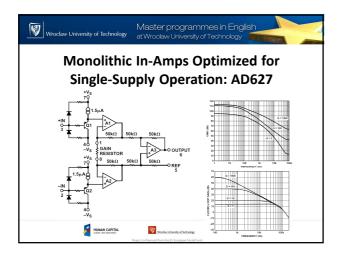














MONOLITHIC DIFFERENCE AMPLIFIERS								
Product	Table 4-1. Latest Generation	of Analog Power Supply Current Typ	-3 dB BW Typ (G = 10)	CMR G = 10 (dB) Min	nps Sum Input Offset Voltage Max	narized <sup>1</sup> V <sub>OS</sub> Drift (μV/°C) Max	$RTINoise2(nV/\sqrt{Hz})(G = 10)$	
AD8202 AD8203 AD8205 AD8206 AD8210 AD8212 AD8213 AD8130 AD628 AD629 AD626 AMP03	$\begin{array}{l} S_{*,2} \equiv 3 V \ CMV, G=20\\ S_{*,2} \equiv 3 V \ CMV, G=14\\ S_{*,3} \equiv 3 V \ CMV, G=50\\ S_{*,5} = 5 V \ CMV, G=50\\ S_{*,5}, G > V \ CMV, G=20\\ S_{*,5}, G > V \ CMV, G=20\\ T \ OHt annel\\ 270 \ MHz \ receiver\\ High \ CMV\\ G=1\\ High \ CMV\\ G=1\\ \end{array}$	$\begin{array}{c} 250 \ \mu A \\ 250 \ \mu A \\ 1 \ mA \\ 1 \ mA \\ 500 \ \mu A \\ 200 \ \mu A \\ 1.3 \ mA^{11} \\ 12 \ mA \\ 1.6 \ mA \\ 0.9 \ mA \\ 1.5 \ mA \\ 3.5 \ mA \end{array}$	50 kHz 60 kHz <sup>7</sup> 50 kHz <sup>8</sup> 100 kHz <sup>3</sup> 500 kHz 500 kHz 500 kHz 270 MHz 600 kHz <sup>15</sup> 500 kHz 100 kHz 3 MHz	$\begin{array}{c} 80^{3,4,5}\\ 80^{5,7}\\ 80^{4,5,6}\\ 76^{3,9}\\ 100^{3,5}\\ 90\\ 100\\ 83^{12,13}\\ 75^{15}\\ 77^{12}\\ 55^{16}\\ 85^{12}\\ \end{array}$	$\begin{array}{c} 1 \ mV^6 \\ 1 \ mV^6 \\ 2 \ mV^6 \\ 2 \ mV^6 \\ 1 \ mV \\ 1 \ mV \\ 1 \ mV \\ 1.8 \ mV \\ 1.5 \ mV \\ 1 \ mV \\ 500 \ \mu V \\ 400 \ \mu V \end{array}$	10 10 15 typ 5 typ 10 10 3.5 mV 4 6 1 NS	$\begin{array}{c} 300 \ typ^3 \\ 300 \ typ^7 \\ 500 \ typ^8 \\ 500 \ typ^3 \\ 500 \ typ^3 \\ 100 \ typ \\ 12.5 \ typ^{12}, 14 \\ 300 \ typ^{12} \\ 550 \ typ^{12} \\ 250 \ typ^{12} \end{array}$	

